ΡΛΝ	JIT
	SEMI
	CONDUCTOR

Voltage

Features

• Excellent FOM • Logic Level Drive

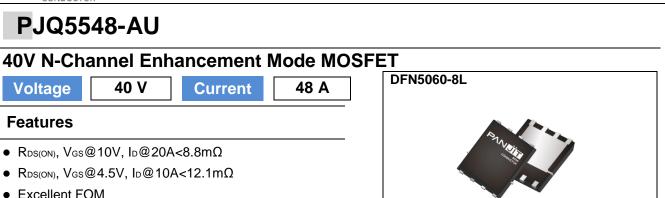
PJQ5548-AU

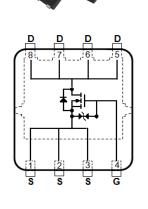
40 V

• Rds(on), Vgs@10V, Id@20A<8.8mΩ • Rds(ON), Vgs@4.5V, Id@10A<12.1mΩ

Current

48 A





• AEC-Q101 qualified • Lead free in compliance with EU RoHS 2.0

• Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40	- v	
Gate-Source Voltage		V _{GS}	±20	V	
Continuous Drain Current ^(Note 3)	T _C =25°C		48		
	Tc=100°C	I _D	34	Α	
Pulsed Drain Current(Note 1)	T _c =25°C	I _{DM}	192		
Power Dissipation	T _c =25°C	<u> </u>	36		
	Tc=100°C	PD	18	W	
Continuous Drain Current ^(Note 4)	T _A =25°C		14.5		
	T _A =70°C	ID ID	12	— A	
Power Dissipation	T _A =25 [°] C	Da	3.3	۱۸/	
	T _A =70°C	PD	2.3	W	
Single Pulse Avalanche Energy ^(Note 5)		Eas	42	mJ	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	$R_{ extsf{ heta}JC}$	4.2	°C/W	
	Junction to Ambient	R _{0JA}	45		



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	Ň
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =50uA	1.1	1.6	2.3	V
Drain-Source On-State Resistance	_	V _{GS} =10V, I _D =20A	-	7	8.8	mΩ
	R _{DS(on)}	V _{GS} =4.5V, I _D =10A		9.3	12.1	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =40V, V_{GS} =0V	-	-	1	uA
		V _{GS} =±20V, V _{DS} =0V	-	-	±10	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±10V, V _{DS} =0V	-	-	±1	
Dynamic ^(Note 6)	_			-	-	
Total Gate Charge	Qg		-	13	-	nC
Gate-Source Charge	Qgs	$V_{DS}=32V$, $I_{D}=20A$,	-	3	-	
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	2	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V,	-	778	-	
Output Capacitance	Coss		-	180	-	pF
Reverse Transfer Capacitance	Crss	f=1MHz	-	25	-	
Gate resistance	Rg	f=1MHz	-	1.6	-	Ω
Turn-On Delay Time	td _(on)		-	7	-	
Turn-On Rise Time	tr	$V_{DS}=32V$, $I_D=20A$, $V_{GS}=10V$, $R_G=3\Omega$ (Note 2)	-	78	-	ns
Turn-Off Delay Time	td(off)		-	26	-	
Turn-Off Fall Time	tf		-	56	-	
Drain-Source Diode						
Diode Forward Current	Is	T _c =25°C	-	-	48	
Pulsed Diode Forward Current	I _{SM}	10=20 U	-	-	192	A
Diode Forward Voltage	V _{SD}	Is=20A, V _{GS} =0V	-	0.9	1.3	V
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =20A	-	20	-	ns
Reverse Recovery Charge	Qrr	dl _s /dt=100A/us	-	10	-	nC

NOTES :

- 1. Pulse width<100us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}$ =4.2°C/W.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS}=13A, V_{DD}=30V, V_{GS}=10V, Starting T_J=25^{\circ}C.
- 6. Guaranteed by design, not subject to production testing.



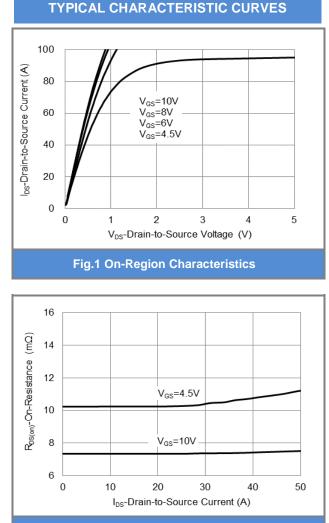
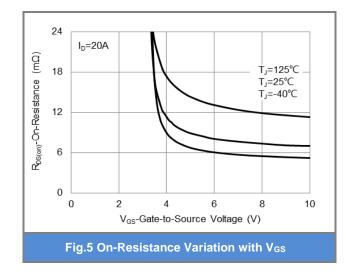
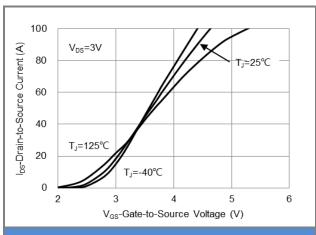
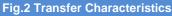


Fig.3 On-Resistance vs. Drain Current







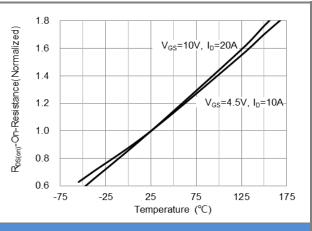


Fig.4 On-Resistance vs. Junction temperature

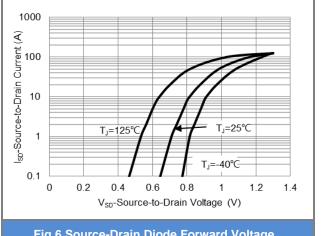
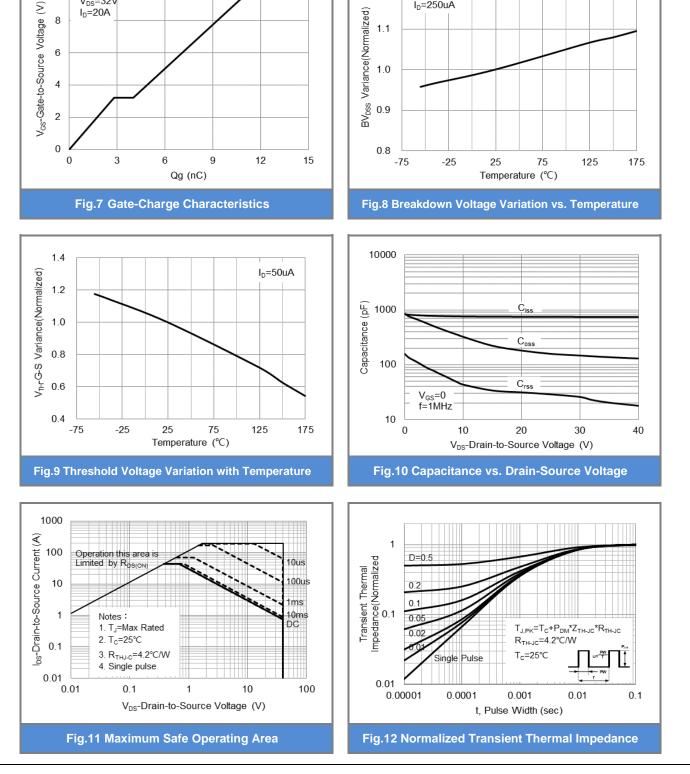


Fig.6 Source-Drain Diode Forward Voltage

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1.2

1.1

I_D=250uA

PJQ5548-AU

V_{DS}=32V

I_D=20A



10

8

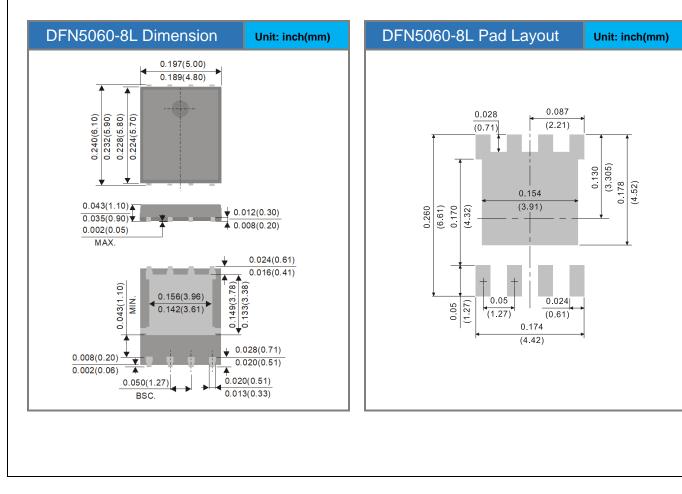




Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ5548-AU_R2_002A1	DFN5060-8L	3K pcs / 13" reel	Q5548	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout



January 30,2023



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